

MN4027B/MN4027BS

Dual J-K Flip-Flop

■ Outline

The MN4027B/S has two built-in circuits of J-K flip-flops in one chip. The respective flip-flop has independent J, K, set, clear, and clock outputs and complementary outputs (O , \bar{O}).

In the J-K mode, the clear input and the set input both become the "L" level, and the output changes at the rise of the clock pulse according to the state of J and state of K.

This dual J-K flip-flop is equivalent to Motorola's MC14027B and RCA's CD4027B.

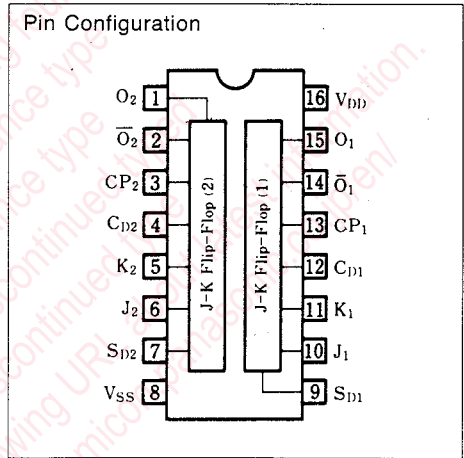
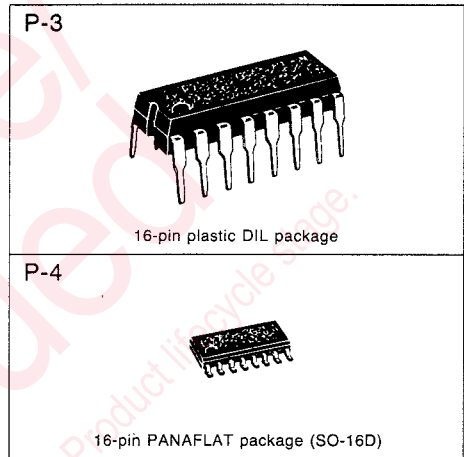
■ Truth Table

Input					Output	
S_D	C_D	CP	J	K	O_{n+1}	\bar{O}_{n+1}
L	L		L	L	no change	
L	L		H	L	H	L
L	L		L	H	L	H
L	L		H	H	\bar{O}_n	O_n
H	L	x	x	x	H	L
L	H	x	x	x	L	H
H	H	x	x	x	H	H
L	L		x	x	no change	

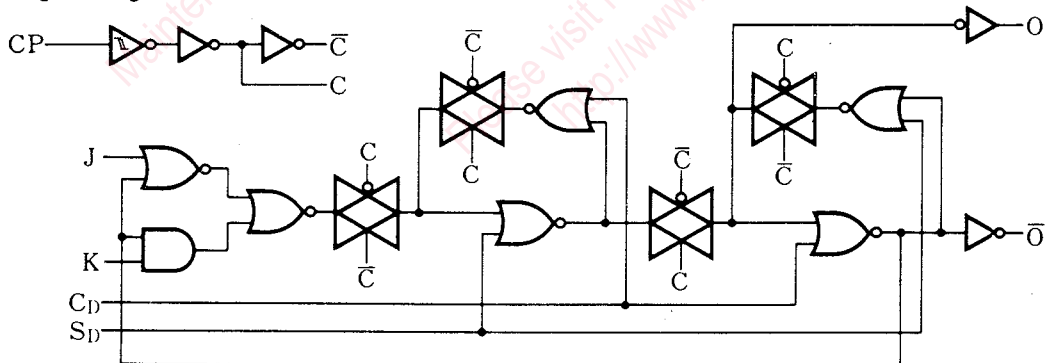
Note) x : don't care

Pin description

- J, K : Synchronous input
- CP : Clock input ()
- S_D : Asynchronous set input
- C_D : Asynchronous clear input
- O , \bar{O} : Output (complementary)



■ Logic Diagram



■ Absolute Maximum Ratings (Ta=25°C)

Item	Symbol	Rating	Unit
Supply voltage	V_{DD}	-0.5~+18	V
Input voltage	V_I	-0.5~ $V_{DD}+0.5^*$	V
Output pin voltage	V_O	-0.5~ $V_{DD}+0.5^*$	V
Peak input · output pin current	$\pm I_I$	max. 10	mA
Power dissipation (per package)	Ta = -40~+60°C	max. 400	mW
	Ta = +60~+80°C	Decrease to 200mW at the rate of 8mW/°C	
Power dissipation (per output pin)	P_D	max. 100	mW
Operating ambient temperature	T_{opr}	-40~+85	°C
Storage temperature	T_{stg}	-65~+150	°C

* $V_{DD}+0.5V$ should be lower than 18V.

■ DC Characteristics ($V_{SS}=0V$)

Item	V_{DD} (V)	Symbol	Condition	Ta = -40°C		Ta = 25°C		Ta = 85°C		Unit	
				min.	max.	min.	max.	min.	max.		
Static supply current	5	I_{DD}	$V_I = V_{SS}$ or V_{DD}	—	4	—	4	—	30	μA	
	10			—	8	—	8	—	60		
	15			—	16	—	16	—	120		
Output voltage low level	5	V_{OL}	$V_I = V_{SS}$ or V_{DD} $ I_{O} < 1\mu A$	—	0.05	—	0.05	—	0.05	V	
	10			—	0.05	—	0.05	—	0.05		
	15			—	0.05	—	0.05	—	0.05		
Output voltage high level	5	V_{OH}	$V_I = V_{SS}$ or V_{DD} $ I_{O} < 1\mu A$	4.95	—	4.95	—	4.95	—	V	
	10			9.95	—	9.95	—	9.95	—		
	15			14.95	—	14.95	—	14.95	—		
Input voltage low level	5	V_{IL}	$ I_{O} < 1\mu A$	$V_O = 0.5V$ or $4.5V$ $V_O = 1V$ or $9V$ $V_O = 1.5V$ or $13.5V$	—	1.5	—	1.5	—	1.5	V
	10				—	3	—	3	—	3	
	15				—	4	—	4	—	4	
Input voltage high level	5	V_{IH}	$ I_{O} < 1\mu A$	$V_O = 0.5V$ or $4.5V$ $V_O = 1V$ or $9V$ $V_O = 1.5V$ or $13.5V$	3.5	—	3.5	—	3.5	—	V
	10				7	—	7	—	7	—	
	15				11	—	11	—	11	—	
Output current low level	5	I_{OL}	$V_O = 0.4V, V_I = 0$ or $5V$ $V_O = 0.5V, V_I = 0$ or $10V$ $V_O = 1.5V, V_I = 0$ or $15V$	0.52	—	0.44	—	0.36	—	mA	
	10			1.3	—	1.1	—	0.9	—		
	15			3.6	—	3	—	2.4	—		
Output current high level	5	$-I_{OH}$	$V_O = 4.6V, V_I = 0$ or $5V$ $V_O = 9.5V, V_I = 0$ or $10V$ $V_O = 13.5V, V_I = 0$ or $15V$	0.52	—	0.44	—	0.36	—	mA	
	10			1.3	—	1.1	—	0.9	—		
	15			3.6	—	3	—	2.4	—		
Output current high level	5	$-I_{OH}$	$V_O = 2.5V, V_I = 0$ or $5V$	1.7	—	1.4	—	1.1	—	mA	
Input leakage current	15	$\pm I_I$	$V_I = 0$ or $15V$	—	0.3	—	0.3	—	1	μA	

■ Switching Characteristics (Ta=25°C, VSS=0V, CL=50pF)

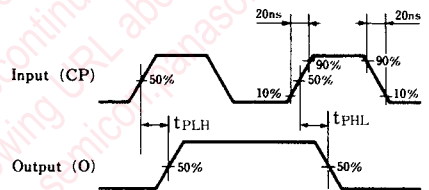
Item	VDD(V)	Symbol	min.	typ.	max.	Unit
Output rise time	5	t _{TLH}	—	60	180	ns
	10		—	30	90	
	15		—	20	60	
Output fall time	5	t _{THL}	—	60	180	ns
	10		—	30	90	
	15		—	20	60	
Propagation time (CP→O, \bar{O}) (H→L)	5	t _{PLH}	—	115	345	ns
	10		—	50	150	
	15		—	35	105	
Propagation time (CP→O, \bar{O}) (L→H)	5	t _{PHL}	—	115	345	ns
	10		—	50	150	
	15		—	35	105	
Propagation time (S _D →O)	5	t _{PHL}	—	75	225	ns
	10		—	35	105	
	15		—	25	75	
Propagation time (C _D →O)	5	t _{PHL}	—	130	390	ns
	10		—	50	150	
	15		—	35	105	
Minimum set-up time (J, K→CP)	5	t _{su}	—	50	150	ns
	10		—	15	45	
	15		—	10	30	
Minimum clear pulse width	5	t _{WSDH}	—	40	120	ns
	10	t _{WCDH}	—	20	60	
Minimum pre-set pulse width	5	t _{WSDH}	—	40	120	ns
	15	t _{WCDH}	—	15	45	
Maximum clock frequency	5	f _{max}	3	6	—	MHz
	10		7	15	—	
	15		11	22	—	
Input capacitance		C _I	—	—	7.5	pF

● Switching time measuring circuit

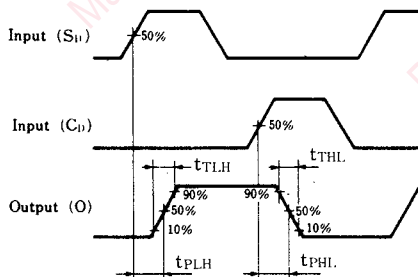
Test No.	J	K	C _D	S _D	CP
1	H	H	L	L	P.G. 1
2	H	H	P.G. 1	P.G. 2	H
3	P.G. 1	P.G. 1	L	L	P.G. 2

Note) P.G. = Pulse generator

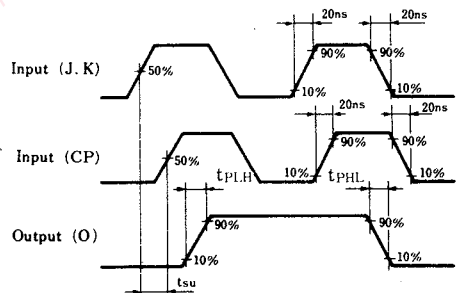
Test No.1 waveforms



Test No.2 waveforms



Test No.3 waveforms



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